

40A 200V SchottkyBarrierDiode

1 Description

Dual center tab Schottky rectifier suited for High Frequency server and telecom base station SMPS. Packaged in TO-3P/TO-247, this device combines

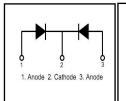
high current rating and low volume to enhance both reliability and power density of the application.

2 Features

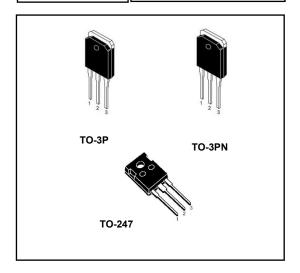
- High junction temperature capabiliy
- Low leakage current
- Low thermal resistance
- High frequency operation
- Avalanche specification

3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose



 V_{BR} = 200V $V_{F}(\text{single})$ = 0.95V $I_{F(AV)}(\text{single})$ = 20A



4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25 $^{\circ}$ C,unless otherwise noted)

PARAMETER		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage		V _{RRM}	200	V
RMS Reverse Voltage		V _{R(RMS)}	160	V
DC Blocking Voltage		V _R	200	V
Average Rectified Forward Current(single)	T -420°C		20	Α
Average Rectified Forward Current(double)		I _{F(AV)}	40	Α
Repetitive Peak Surge Current(single)		I _{FRM}	30	Α
Nonrepetitive Peak Surge Current(single) tp=8.3ms		I _{FSM}	250	Α
Avalanche Energy(single) L=1mH		E _{AS}	50	mJ
Operating Junction Temperature Range		Tj	- 55∼150	$^{\circ}\!\mathbb{C}$
Storage Temperature Range		T _{stg}	- 55∼150	$^{\circ}$ C

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VAL	.UE	UNIT
PARAMETER	STIVIDUL	TO-3P/3PN	TO-247	UNII
Thermal Resistance, Junction to Case-sink	R _{thJC}	0.90	0.85	°C/W



4.3 Electrical Characteristics

(Tc=25[°]C,unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous	V _F	I _F = 20A	-	0.88	0.95	V
Forward Voltage		I _F = 20A, T _C = 125℃	-	-	0.85	V
		I _F = 30A	-	0.91	1.1	V
Maximum Instantaneous	I _R	V _R = 200V	-	2	100	uA
Reverse		V _R = 200V, TC = 125℃	-	-	20	mA
Total capacitance	Ctot	V _R =10V f=1MHz	-	180	-	pF
DC Blocking Voltage	V_{BR}	I _R =100uA	205	240	-	V

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300µs, D = 2%).

IR = Instantaneous reverse current.

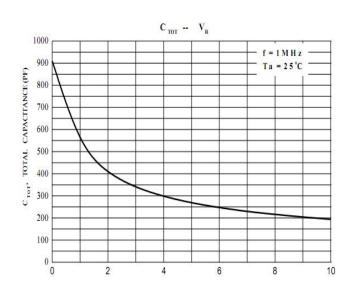
 $R\theta JC$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

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5 Typical characteristics diagrams



 $I_R - V_R$ 10⁴ IR, INSTANTANEOUS REVERSE CURRENT (uA) 10³ 10² 75°C 10¹ $Ta = 25^{\circ}C$ 10° 10⁻¹ 40 60 80 100 120 140 160 180 200 V_R, INSTANTANEOUS REVERSE VOLTAGE(V)

FIGURE 1. Total capacitance vs Voltage

FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



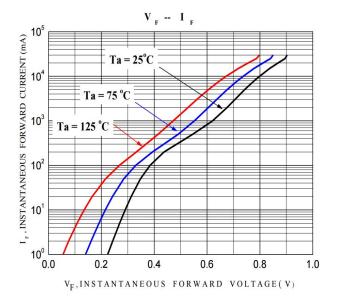


FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

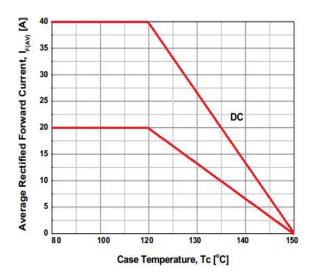


FIGURE 4. CURRENT DERATING CURVE

6 Typical Test Circuit and Waveform

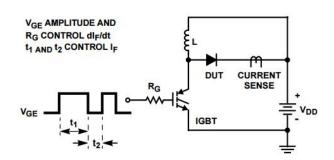


FIGURE 5. trr TEST CIRCUIT

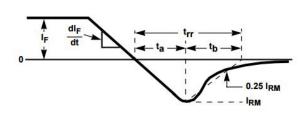


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

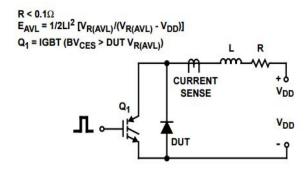


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

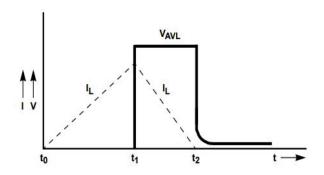
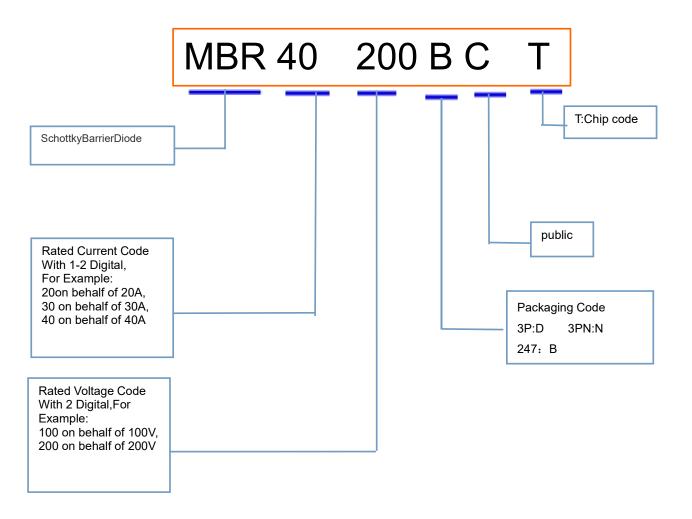


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



7 Product Names Rules



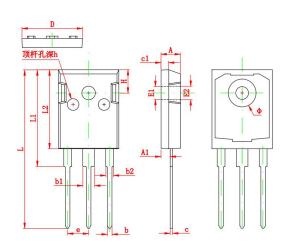
8 Product Specifications and Packaging Models

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MBR40200CT	TO-3P	MBR40200CT	Pb-free	Tube	300/box
MBR40200BCT	TO-247	MBR40200BCT	Pb-free	Tube	300/box
MBR40200NCT	TO-3PN	MBR40200NCT	Pb-free	Tube	300/box



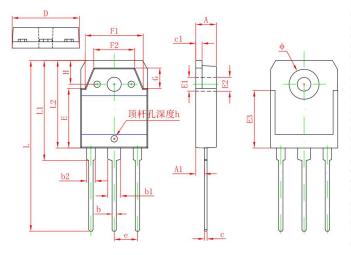
9 Dimensions

TO-247 PACKAGE OUTLINE DIMENSIONS



C.u. b.a.l	Dimensions In Millimeters		Dimensions In Inches		
Symbol	M in	Max	Min	Max	
Α	4.600	5.000	0.181	0.197	
A 1	2.200	2.600	0.087	0.102	
b	0.800	1.200	0.031	0.047	
b 1	2.800	3.200	0.110	0.126	
b 2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.450	1.650	0.057	0.065	
D	15.450	15.850	0.608	0.624	
E	13.700	14.100	0.539	0.555	
E 1	3.200 REF		0.126 REF		
E 2	3.300	3.300 REF 0.130 RE		REF	
E 3	13.45	0 REF	0.530 REF		
F1	13.400	13.800	0.528	0.543	
F2	9.400	9.800	0.370	0.386	
L	39.900	40.300	1.571	1.587	
L1	23.200	23.600	0.913	0.929	
L2	20.300	20.600	0.799	0.811	
Φ	6.900	7.100	0.272	0.280	
G	5.150	5.550	0.203	0.219	
е	5.450 TYP		0.21	5 TYP	
Н	5.000	REF	0.197	7 REF	
h	0.000	0.300	0.000	0.012	

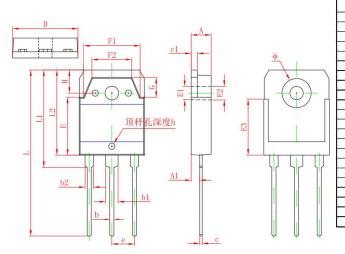
TO-3P PACKAGE OUTLINE DIMENSIONS



C b a l	Dimensions In Millimeters		Dimensions In Inches		
Symbol	M in	Max	M in	Max	
Α	4.600	5.000	0.181	0.197	
A 1	1.200	1.600	0.047	0.063	
b	0.800	1.200	0.031	0.047	
b 1	2.800	3.200	0.110	0.126	
b 2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.450	1.650	0.057	0.065	
D	15.450	15.850	0.608	0.624	
E	13.700	14.100	0.539	0.555	
E 1	3.200 REF		0.126 REF		
E 2	3.300 REF		0.130 REF		
E 3	13.45	0 REF	0.530 REF		
F1	13.400	13.800	0.528	0.543	
F2	9.400	9.800	0.370	0.386	
L	39.900	40.300	1.571	1.587	
L1	23.200	23.600	0.913	0.929	
L2	20.300	20.600	0.799	0.811	
Φ	6.900	7.100	0.272	0.280	
G	5.150	5.550	0.203	0.219	
е	5.450 TYP		0.215 TYP		
Н	5.000	REF	0.197 REF		
h	0.000	0.300	0.000	0.012	



TO-3PN PACKAGE OUTLINE DIMENSIONS



C., b . l	Dimensions In Millimeters		Dimension	s In Inches
Symbol	M in	Max	M in	Max
Α	4.600	5.000	0.181	0.197
A 1	2.200	2.600	0.087	0.102
b	0.800	1.200	0.031	0.047
b 1	2.800	3.200	0.110	0.126
b 2	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.450	1.650	0.057	0.065
D	15.450	15.850	0.608	0.624
E	13.700	14.100	0.539	0.555
E 1	3.200 REF		0.126 REF	
E 2	3.300 REF		0.130 REF	
E 3	13.45	0 REF	0.530 REF	
F1	13.400	13.800	0.528	0.543
F2	9.400	9.800	0.370	0.386
L	39.900	40.300	1.571	1.587
L1	23.200	23.600	0.913	0.929
L2	20.300	20.600	0.799	0.811
Φ	6.900	7.100	0.272	0.280
G	5.150	5.550	0.203	0.219
е	5.45	0 TYP	0.215	TYP
Н	5.000	REF	0.197	REF
h	0.000	0.300	0.000	0.012

10 Attentions

- Jiangsu Donghai Semiconductor Technology Co., Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

Date	REV.	Description	Page
2017.08.29	1.0	Original	